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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: LEE, Jae-Gab; JEONG, Chang-Oh; SUNG, Myung-Mo;  
 YANG, Hee-Jung; CHO, Beom-Seok  
 Assignee: SAMSUNG ELECTRONICS CO., LTD.  
 Title: THIN FILM TRANSISTOR SUBSTRATE AND METHOD FOR  
 FORMING METAL WIRE THEREOF  
 Int'l. Application No.: PCT/KR2003/000599 Int'l. Filing Date: 03/26/2003  
 Application No.: Unknown Filing Date: Herewith  
 Examiner: Unknown Group Art Unit: Unknown  
 Docket No.: AB-1448 US

San Jose, California  
 June 16, 2005

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 Commissioner for Patents  
 P.O. Box 1450  
 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)

Dear Sir:

Pursuant to 37 C.F.R. § § 1.56, 1.97 and 1.98, the documents listed on the accompanying PTO Form-1449 are called to the attention of the Examiner for the above-identified application. Copies of the documents are enclosed with the exception of any U.S. patents and the reference cited on the PTO Form-1449 at AR, which is not available at this time. The documents were cited on the International Search Report for International Application No. PCT/KR2003/000599, which is the international stage of the present application.

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3. admission that the information cited herein, or is considered to be,  
material to patentability as defined in § 1.56(b).

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Respectfully submitted,



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U.S. Department of Commerce, Patent and Trademark Office					Atty. Docket No.		Application No.	
					AB-1448 US		Unknown	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT					Applicant(s)			
(Use several sheets if necessary)					LEE, Jae-Gab et al.			
					Filing Date		Group	
					Herewith		Unknown	
U.S. Patent Documents								
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate	
	AA	US 2002/0045289	04/18/2002	Dimitrakopoulos et al.				
	AB	US 2002/0084252	07/04/2002	Buchwalter et al.				
	AC							
	AD							
	AE							
	AF							
	AG							
	AH							
	AI							
	AJ							
	AK							
Foreign Patent Documents								
							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
	AL	WO 01/00538 A2	01/04/2001	PCT				
	AM							
	AN							
	AO							
	AP							
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)								
	AQ	Patent Abstracts of Japan, Publication No. 2000-330134, 11/30/2000						
*	AR	Collet, J. et al., "Performances of sexithiophene based thin-film transistor using self-assembled monolayers," Materials Research Society Symposium Proceedings (1998), 488 (Electrical, Optical, and Magnetic Properties of Organic Solid-State Materials IV), 407-412, ISSN: 0272-9172 <i>abstract</i>						
	AS							
Examiner			Date Considered					
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